

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3521	((438/149.ccls. or 257/70.ccls. or 257/72.ccls. or 257/350.ccls. or 257/627.ccls. or 257/98.ccls. or 257/59.ccls. or 257/79.ccls. ) and (gate) and (source or drain)) and (insulator or dielectric or insulative or oxide)) and electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 00:20
L2	524	(semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (gate near3 (wire or wiring))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 00:20
L3	3443	1 not L2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 00:20
L4	1287	((semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (wordline or (word adj line))) not ((semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode). and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (gate near3 (wire or wiring)) )	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 00:20
L5	3413	3 not L4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 00:20
L6	1064	3 not L4	US-PGPUB	OR	OFF	2005/07/13 00:21
L7	2293	3 not L4	USPAT	OR	OFF	2005/07/13 00:27
S1	1	"6303963".pn.	USPAT	OR	OFF	2003/08/06 18:20
S2	1	"6515310".pn.	USPAT	OR	OFF	2003/02/11 17:50
S3	1	"6504174".pn.	USPAT	OR	OFF	2003/02/11 17:51
S4	1	'6300927".pn.	USPAT	OR	OFF	2003/02/11 17:51
S5	1	"6306694".pn.	USPAT	OR	OFF	2003/02/11 17:51

S6	1	"6407430".pn.	USPAT	OR	OFF	2003/02/11 17:52
S7	1	"6501098".pn.	USPAT	OR	OFF	2003/02/11 17:52
S8	1	"6469317".pn.	USPAT	OR	OFF	2003/02/11 17:52
S9	1	"6483484".pn.	USPAT	OR	OFF	2003/02/11 17:53
S10	0	"6524895".pn.	USPAT	OR	OFF	2003/02/11 17:53
S11	0	"6524895".pn.	USPAT	OR	OFF	2003/02/11 17:53
S12	1	"6392628".pn.	USPAT	OR	OFF	2003/02/11 17:54
S13	1	"6278131".pn.	USPAT	OR	OFF	2003/02/11 17:54
S14	1	"6160271".pn.	USPAT	OR	OFF	2003/02/11 17:54
S15	1	"6310363".pn.	USPAT	OR	OFF	2003/02/11 17:54
S16	1	"6204518".pn.	USPAT	OR	OFF	2003/02/11 17:55
S17	1	"6506635".pn.	USPAT	OR	OFF	2003/02/11 17:55
S18	1	"6448135".pn.	USPAT	OR	OFF	2003/02/11 17:55
S19	1	"6458635".pn.	USPAT	OR	OFF	2003/02/11 17:55
S20	1	"6468842".pn.	USPAT	OR	OFF	2003/02/11 17:56
S21	1	"6407431".pn.	USPAT	OR	OFF	2003/02/11 17:56
S22	1	"6465268".pn.	USPAT	OR	OFF	2003/02/11 17:56
S23	1	"6482687".pn.	USPAT	OR	OFF	2003/02/11 17:57
S24	1	"6496171".pn.	USPAT	OR	OFF	2003/02/11 17:57
S25	1	"6362866".pn.	USPAT	OR	OFF	2003/02/11 17:57
S26	1	"6376333".pn.	USPAT	OR	OFF	2003/02/11 17:57
S27	1	"20010029070".pn.	US-PGPUB	OR	OFF	2003/02/11 17:58
S28	1	"20010040655".pn.	US-PGPUB	OR	OFF	2003/02/11 17:58
S29	1	"20010025960".pn.	US-PGPUB	OR	OFF	2003/02/11 17:59
S30	1	"20010035526".pn.	US-PGPUB	OR	OFF	2003/02/11 17:59
S31	1	"20010022677".pn.	US-PGPUB	OR	OFF	2003/02/11 17:59
S32	1	"20020175376".pn.	US-PGPUB	OR	OFF	2003/02/11 17:59
S33	1	"20010031074".pn.	US-PGPUB	OR	OFF	2003/02/11 18:00
S34	1	"20010029069".pn.	US-PGPUB	OR	OFF	2003/02/11 18:00
S35	1	"20010026846".pn.	US-PGPUB	OR	OFF	2003/02/11 18:00
S36	1	"20010026964".pn.	US-PGPUB	OR	OFF	2003/02/11 18:01
S37	1	"20010019154".pn.	US-PGPUB	OR	OFF	2003/02/11 18:01
S38	1	"20020006711".pn.	US-PGPUB	OR	OFF	2003/02/11 18:01
S39	1	"20020031874".pn.	US-PGPUB	OR	OFF	2003/02/11 18:02
S40	1	"20010030511".pn.	US-PGPUB	OR	OFF	2003/02/11 18:02
S41	1	"20010055384".pn.	US-PGPUB	OR	OFF	2003/02/11 18:02
S42	1	"20010018239".pn.	US-PGPUB	OR	OFF	2003/02/11 18:03
S43	1	"20010043168".pn.	US-PGPUB	OR	OFF	2003/02/11 18:03

S44	1	"20020126108".pn.	US-PGPUB	OR	OFF	2003/02/11 18:03
S45	1	"20020044111".pn.	US-PGPUB	OR	OFF	2003/02/11 18:04
S46	0	"2002004796".pn.	US-PGPUB	OR	OFF	2003/02/11 18:04
S47	0	"2001004796".pn.	US-PGPUB	OR	OFF	2003/02/11 18:05
S48	1	"20020011796".pn.	US-PGPUB	OR	OFF	2003/02/11 18:05
S49	1	"20010040565".pn.	US-PGPUB	OR	OFF	2003/02/11 18:05
S50	1	"20010055841".pn.	US-PGPUB	OR	OFF	2003/02/11 18:06
S51	1	"20020014624".pn.	US-PGPUB	OR	OFF	2003/02/11 18:06
S52	1	"20020044124".pn.	US-PGPUB	OR	OFF	2003/02/11 18:06
S53	1	"20020027229".pn.	US-PGPUB	OR	OFF	2003/02/11 18:06
S54	1	"20020014628".pn.	US-PGPUB	OR	OFF	2003/02/11 18:07
S55	1	"20020005696".pn.	US-PGPUB	OR	OFF	2003/02/11 18:07
S56	1	"20020048829".pn.	US-PGPUB	OR	OFF	2003/02/11 18:07
S57	1	"20020045945".pn.	US-PGPUB	OR	OFF	2003/02/11 18:08
S58	1	"20010045945".pn.	US-PGPUB	OR	OFF	2003/02/11 18:08
S59	1	"20020021266".pn.	US-PGPUB	OR	OFF	2003/02/11 18:08
S60	1	"20020005905".pn.	US-PGPUB	OR	OFF	2003/02/11 18:08

S61	54	(US-6303963-\$ or US-6515310-\$ or US-6504174-\$ or US-6300927-\$ or US-6306694-\$ or US-6407430-\$ or US-6501098-\$ or US-6469317-\$ or US-6483484-\$ or US-6392628-\$ or US-6278131-\$ or US-6160271-\$ or US-6310363-\$ or US-6204518-\$ or US-6506635-\$ or US-6448135-\$ or US-6458635-\$ or US-6468842-\$ or US-6407431-\$ or US-6465268-\$ or US-6482687-\$ or US-6496171-\$ or US-6362866-\$ or US-6376333-\$).did. or (US-20010029070-\$ or US-20010040655-\$ or US-20010025960-\$ or US-20010035526-\$ or US-20010022677-\$ or US-20020175376-\$ or US-20010031074-\$ or US-20010029069-\$ or US-20010026846-\$ or US-20010026964-\$ or US-20010019154-\$ or US-20020006711-\$ or US-20020031874-\$ or US-20010030511-\$ or US-20010055384-\$ or US-20010043168-\$ or US-20020126108-\$ or US-20020044111-\$ or US-20020011796-\$ or US-20010040565-\$ or US-20010055841-\$ or US-20020014624-\$ or US-20020044124-\$ or US-20020027229-\$ or US-20020014628-\$ or US-20020005696-\$).did. or (US-20020048829-\$ or US-20010045945-\$ or US-20020021266-\$ or US-20020005905-\$).did.	US-PGPUB; USPAT	OR	OFF	2003/02/11 18:09
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S62	28	(US-6506635-\$ or US-6504174-\$ or US-6501098-\$ or US-6483484-\$ or US-6469317-\$ or US-6407430-\$ or US-6306694-\$ or US-6303963-\$ or US-6278131-\$ or US-6160271-\$).did. or (US-20020048829-\$ or US-20020044124-\$ or US-20020044111-\$ or US-20020031874-\$ or US-20020014628-\$ or US-20020014624-\$ or US-20020005905-\$ or US-20010055841-\$ or US-20010055384-\$ or US-20010043168-\$ or US-20010040655-\$ or US-20010035526-\$ or US-20010031074-\$ or US-20010030511-\$ or US-20010029070-\$ or US-20010029069-\$ or US-20010026964-\$ or US-20010025960-\$).did.	US-PGPUB; USPAT	OR	OFF	2003/02/11 18:27
S63	1	"6148685"	EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/02/19 18:34
S64	109	257/70.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:02
S65	1156	257/72.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:03
S66	842	257/350.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:03
S67	428	257/627.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:03
S68	1473	257/98.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/08/06 18:46
S69	1	"6358631":PN	USPAT	OR	OFF	2003/08/06 18:50

S70	1	"5294810".PN.	USPAT	OR	OFF	2003/08/06 18:50
S71	1319	257/59.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/08/06 22:24
S72	749	257/79.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/08/06 22:24
S73	1099	438/149.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:02
S74	124	257/70.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:02
S75	1489	257/72.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:03
S76	997	257/350.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:03
S77	462	257/627.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:03
S78	1756	257/98.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:03
S79	1596	257/59.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:03
S80	1038	257/79.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:03

S81	467	(semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (gate near3 (wire or wiring))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/12 20:53
S82	1208	(semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (wordline or (word adj line))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/04 13:13
S83	1088	((semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (wordline or (word adj line)) ) not ((semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (gate near3 (wire or wiring)) )	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/12 21:03
S84	7183	438/149.ccls. or 257/70.ccls. or 257/72.ccls. or 257/350.ccls. or 257/627.ccls. or 257/98.ccls. or 257/59.ccls. or 257/79.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:13
S85	3654	(438/149.ccls. or 257/70.ccls. or 257/72.ccls. or 257/350.ccls. or 257/627.ccls. or 257/98.ccls. or 257/59.ccls. or 257/79.ccls. ) and (gate) and (source or drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:13
S86	3242	((438/149.ccls. or 257/70.ccls. or 257/72.ccls. or 257/350.ccls. or 257/627.ccls. or 257/98.ccls. or 257/59.ccls. or 257/79.ccls. ) and (gate) and (source or drain)) and (insulator or dielectric or insulative or oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:14

S87	2820	((438/149.ccls. or 257/70.ccls. or 257/72.ccls. or 257/350.ccls. or 257/627.ccls. or 257/98.ccls. or 257/59.ccls. or 257/79.ccls. ) and (gate) and (source or drain)) and (insulator or dielectric or insulative or oxide)) and electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 00:19
S88	1449	(((438/149.ccls. or 257/70.ccls. or 257/72.ccls. or 257/350.ccls. or 257/627.ccls. or 257/98.ccls. or 257/59.ccls. or 257/79.ccls. ) and (gate) and (source or drain)) and (insulator or dielectric or insulative or oxide)) and electrode) and (gate near3 (insulator or dielectric or oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/04 13:14
S89	1425	((((438/149.ccls. or 257/70.ccls. or 257/72.ccls. or 257/350.ccls. or 257/627.ccls. or 257/98.ccls. or 257/59.ccls. or 257/79.ccls. ) and (gate) and (source or drain)) and (insulator or dielectric or insulative or oxide)) and electrode) and (gate near3 (insulator or dielectric or oxide))) not ((semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (wordline or (word adj line)) )	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:15

S90	1356	(((((438/149.ccls. or 257/70.ccls. or 257/72.ccls. or 257/350.ccls. or 257/627.ccls. or 257/98.ccls. or 257/59.ccls. or 257/79.ccls. ) and (gate) and (source or drain)) and (insulator or dielectric or insulative or oxide)) and electrode) and (gate near3 (insulator or dielectric or oxide))) not ((semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (wordline or (word adj line))) ) not ((semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (gate near3 (wire or wiring))) )	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/18 17:15
S92	1	("5917563").PN.	USPAT	OR	OFF	2005/02/03 23:00
S93	488	(semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (gate near3 (wire or wiring)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/04 15:38
S94	1306	(semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (wordline or (word adj line)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/04 13:20
S95	1184	S94 not S93	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/04 13:14

S96	1594	((((438/149.ccls. or 257/70.ccls. or 257/72.ccls. or 257/350.ccls. or 257/627.ccls. or 257/98.ccls. or 257/59.ccls. or 257/79.ccls. ) and (gate) and (source or drain)) and (insulator or dielectric or insulative or oxide)) and electrode) and (gate near3 (insulator or dielectric or oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/04 13:15
S97	1568	S96 not S95	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/04 13:14
S98	1	("5153685").PN.	USPAT	OR	OFF	2005/02/04 15:38
S99	524	(semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (gate near3 (wire or wiring))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/12 20:54
S100	1287	((semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (wordline or (word adj line))) not ((semiconductor or die or chip or ic or (integrated adj circuit)) and ((source or drain) near3 electrode) and gate and (gate near3 (dielectric or oxide or insulator)) and ((dielectric or insulative or insulator) near3 layer) and (gate near3 (wire or wiring)) )	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/12 21:04